



60V N-Channel Enhancement Mode MOSFET

Voltage

60 V

Current

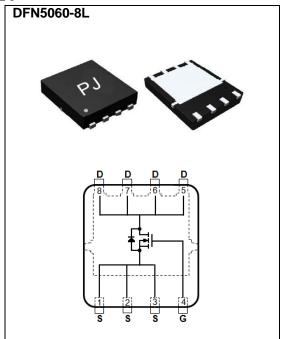
40 A

Features

- $R_{DS(ON)}$, V_{GS} @10V, I_D @15A<21m Ω
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@8A$ < $24m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: DFN5060-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0028 ounces, 0.08 grams
- Marking: Q5466A



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _C =25°C	l _D	40	А	
	T _C =100°C		25		
Pulsed Drain Current (Note 1)	T _C =25°C	I _{DM}	160		
Power Dissipation	T _C =25°C	Po	83	W	
	T _C =100°C		33		
Continuous Drain Current	T _A =25°C	I _D	6.5	Α	
	T _A =70°C		5	Α	
Power Dissipation	T _A =25°C	-	2.0	W	
Power Dissipation	T _A =70°C	Po	1.3		
Single Pulse Avalanche Energy (Note 6)		E _{AS}	42	mJ	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C	
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	$R_{ heta JC}$	1.5	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	$V_{GS}=0V,I_{D}=250uA$	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1.0	1.73	2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =15A	-	18	21	mΩ
		V_{GS} =4.5 V , I_D =8 A	-	21	24	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =60V, V_{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I_{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	Q_g	V _{DS} =30V, I _D =15A, V _{GS} =10V ^(Note 1,2)	-	28	-	nC
Gate-Source Charge	Q_{gs}		-	3.5	-	
Gate-Drain Charge	Q_{gd}		-	6.5	-	
Input Capacitance	Ciss	V _{DS} =20V, V _{GS} =0V, f=1.0MHZ	-	1680	-	pF
Output Capacitance	Coss		-	115	-	
Reverse Transfer Capacitance	Crss	I=1.0IVII IZ	-	85	-	
Turn-On Delay Time	td _(on)		-	7.2	-	
Turn-On Rise Time	t _r	V_{DD} =30V, I_{D} =1A, V_{GS} =10V, R_{G} =6 Ω (Note 1,2)	-	38	-	ns
Turn-Off Delay Time	td _(off)		-	34	-	
Turn-Off Fall Time	t _f		-	8.2	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	ı		-	-	40	А
Diode Forward Current	I _S					
Diode Forward Voltage	V_{SD}	I _S =1A,V _{GS} =0V	-	0.7	1.0	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited.
- 5. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I_{AS} =29A, V_{DD} =25V, V_{GS} =10V
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

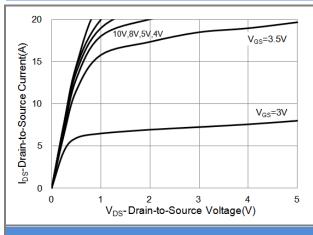


Fig.1 Output Characteristics

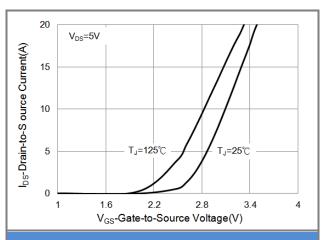


Fig.2 Transfer Characteristics

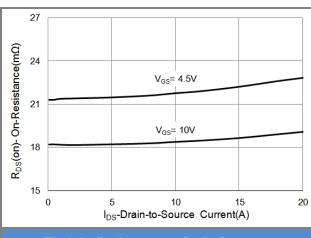


Fig.3 On-Resistance vs. Drain Current

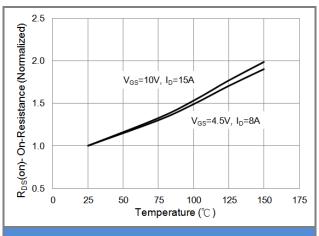
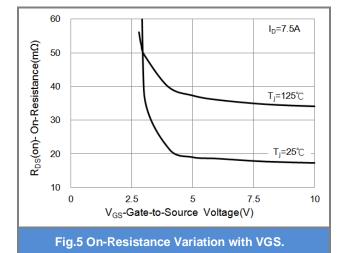


Fig.4 On-Resistance vs. Junction temperature



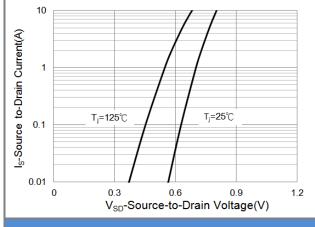


Fig.6 Source-Drain Diode Forward Voltage





TYPICAL CHARACTERISTIC CURVES

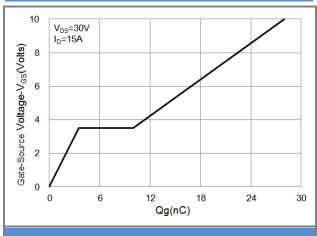


Fig.7 Gate-Charge Characteristics

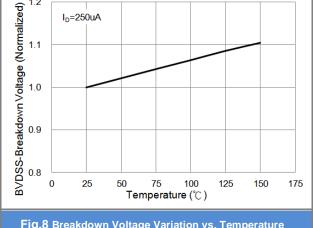


Fig.8 Breakdown Voltage Variation vs. Temperature

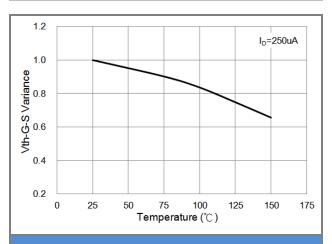


Fig.9 Threshold Voltage Variation with Temperature

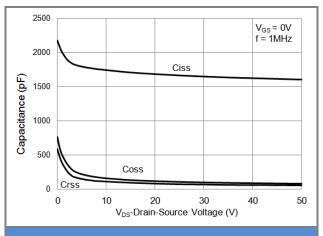
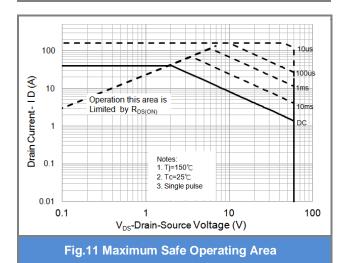


Fig.10 Capacitance vs. Drain-Source Voltage







TYPICAL CHARACTERISTIC CURVES

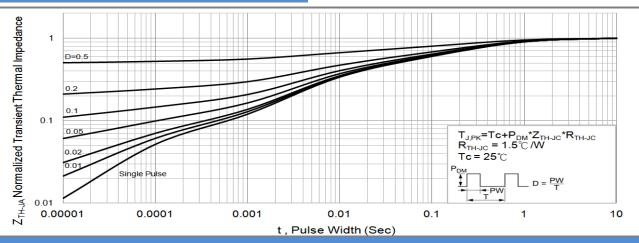


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

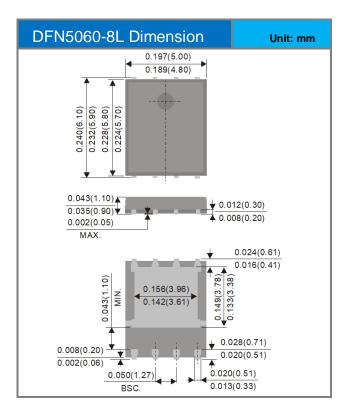


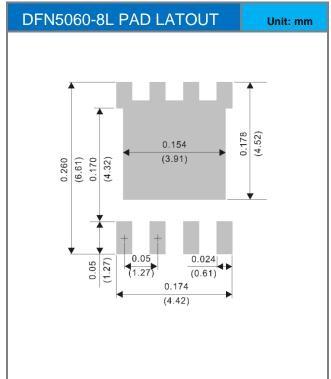


PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version	
PJQ5466A_R2_00001	DFN5060-8L	3000pcs / 13" reel	Q5466A	Halogen free	

Packaging Information & Mounting Pad Layout









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